

ANALOG ELECTRONICS [As per Choice Based Credit System (CBCS) scheme] SEMESTER – III (EC/TC)			
Subject Code	15EC32	IA Marks	20
Number of Lecture Hours/Week	04	Exam Marks	80
Total Number of Lecture Hours	50 (10 Hours per Module)	Exam Hours	03
CREDITS – 04			
Course objectives: This course will enable students to: <ul style="list-style-type: none"> • Explain various BJT parameters, connections and configurations. • Explain BJT Amplifier, Hybrid Equivalent and Hybrid Models. • Explain construction and characteristics of JFETs and MOSFETs. • Explain various types of FET biasing, and demonstrate the use of FET amplifiers. • Construct frequency response of BJT and FET amplifiers at various frequencies. • Analyze Power amplifier circuits in different modes of operation. • Construct Feedback and Oscillator circuits using FET. 			
Modules			RBT Level
Module -1			
BJT AC Analysis: BJT Transistor Modeling, The re transistor model, Common emitter fixed bias, Voltage divider bias, Emitter follower configuration. Darlington connection-DC bias; The Hybrid equivalent model, Approximate Hybrid Equivalent Circuit- Fixed bias, Voltage divider, Emitter follower configuration; Complete Hybrid equivalent model, Hybrid Model.			L1, L2,L3
Module -2			
Field Effect Transistors: Construction and Characteristics of JFETs, Transfer Characteristics, Depletion type MOSFET, Enhancement type MOSFET. FET Amplifiers: JFET small signal model, Fixed bias configuration, Self bias configuration, Voltage divider configuration, Common Gate configuration. Source-Follower Configuration, Cascade configuration.			L1, L2, L3
Module -3			
BJT and JFET Frequency Response: Logarithms, Decibels, Low frequency response – BJT Amplifier with RL, Low frequency response-FET Amplifier, Miller effect capacitance, High frequency response – BJT Amplifier, High frequency response-FET Amplifier, Multistage Frequency Effects.			L1, L2, L3
Module -4			

Feedback and Oscillator Circuits: Feedback concepts, Feedback connection types, Practical feedback circuits, Oscillator operation, FET Phase shift oscillator, Wien bridge oscillator, Tuned Oscillator circuit, Crystal oscillator, UJT construction, UJT Oscillator.	L1,L2, L3
Module -5	
Power Amplifiers: Definition and amplifier types, Series fed class A amplifier, Transformer coupled class A amplifier, Class B amplifier operation and circuits, Amplifier distortion, Class C and Class D amplifiers. Voltage Regulators: Discrete transistor voltage regulation - Series and Shunt Voltage regulators.	L1, L2, L3
<p>Course Outcomes: After studying this course, students will be able to:</p> <ul style="list-style-type: none"> • Describe the working principle and characteristics of BJT, FET, Single stage, cascaded and feedback amplifiers. • Describe the Phase shift, Wien bridge, tuned and crystal oscillators using BJT/FET/UJT. • Calculate the AC gain and impedance for BJT using r_e and h parameters models for CE and CC configuration. • Determine the performance characteristics and parameters of BJT and FET amplifier using small signal model. • Determine the parameters which affect the low frequency and high frequency responses of BJT and FET amplifiers and draw the characteristics. • Evaluate the efficiency of Class A and Class B power amplifiers and voltage regulators. 	
<p>Question paper pattern:</p> <ul style="list-style-type: none"> • The question paper will have ten questions. • Each full question consists of 16 marks. • There will be 2 full questions (with a maximum of Three sub questions) from each module. • Each full question will have sub questions covering all the topics under a module. The students will have to answer 5 full questions, selecting one full question from each module. 	
<p>Text Book:</p> <p>Robert L. Boylestad and Louis Nashelsky, "Electronics devices and Circuit theory", Pearson, 10th/11th Edition, 2012, ISBN:978-81-317-6459-6.</p>	
<p>Reference Books:</p> <ol style="list-style-type: none"> 1. Adel S. Sedra and Kenneth C. Smith, "Micro Electronic Circuits Theory and Application", 5th Edition ISBN:0198062257 2. Fundamentals of Microelectronics, Behzad Razavi, John Wiley ISBN 2013 978-81-265-2307-8 3. J.Millman & C.C.Halkias Integrated Electronics, 2nd edition, 2010, TMH. ISBN 0-07-462245-5 4. K. A. Navas, "Electronics Lab Manual", Volume I, PHI, 5th Edition, 2015, ISBN:9788120351424. 	

DIGITAL ELECTRONICS [As per Choice Based Credit System (CBCS) scheme] SEMESTER - III (EC/TC)			
Subject Code	15EC33	IA Marks	20
Number of Lecture Hours/Week	04	Exam Marks	80
Total Number of Lecture Hours	50 (10 Hours per Module)	Exam Hours	03
CREDITS – 04			
Course objectives: This course will enable students to: <ul style="list-style-type: none"> • Illustrate simplification of Algebraic equations using Karnaugh Maps and Quine-McClusky Techniques. • Design combinational logic circuits. • Design Decoders, Encoders, Digital Multiplexer, Adders, Subtractors and Binary Comparators. • Describe Latches and Flip-flops, Registers and Counters. • Analyze Mealy and Moore Models. • Develop state diagrams Synchronous Sequential Circuits. 			
Modules			RBT Level
Module – 1			
Principles of combination logic: Definition of combinational logic, canonical forms, Generation of switching equations from truth tables, Karnaugh maps-3,4,5 variables, Incompletely specified functions (Don't care terms) Simplifying Max term equations, Quine-McCluskey minimization technique, Quine-McCluskey using don't care terms, Reduced prime implicants Tables.(Text 1, Chapter 3)			L1, L2, L3
Module -2			
Analysis and design of combinational logic: General approach to combinational logic design, Decoders, BCD decoders, Encoders, digital multiplexers, Using multiplexers as Boolean function generators, Adders and subtractors, Cascading full adders, Look ahead carry, Binary comparators.(Text 1, Chapter 4)			L1, L2, L3
Module -3			
Flip-Flops: Basic Bistable elements, Latches, Timing considerations, The master-slave flip-flops (pulse-triggered flip-flops): SR flip-flops, JK flip-flops, Edge triggered flip-flops, Characteristic equations. (Text 2, Chapter 6)			L1,L2
Module -4			
Simple Flip-Flops Applications: Registers, binary ripple counters, synchronous binary counters, Counters based on shift registers, Design of a synchronous counters, Design of a synchronous mod-n counter using clocked T , JK , D and SR flip-flops. (Text 2, Chapter 6)			L1,L2, L3

Module -5	
Sequential Circuit Design: Mealy and Moore models, State machine notation, Synchronous Sequential circuit analysis, Construction of state diagrams, counter design. (Text 1, Chapter 6)	L1, L2, L3
Course Outcomes: After studying this course, students will be able to: <ul style="list-style-type: none"> • Develop simplified switching equation using Karnaugh Maps and Quine-McClusky techniques. • Explain the operation of decoders, encoders, multiplexers, demultiplexers, adders, subtractors and comparators. • Explain the working of Latches and Flip Flops (SR,D,T and JK). • Design Synchronous/Asynchronous Counters and Shift registers using Flip Flops. • Develop Mealy/Moore Models and state diagrams for the given clocked sequential circuits. • Apply the knowledge gained in the design of Counters and Registers. 	
Question paper pattern: <ul style="list-style-type: none"> • The question paper will have ten questions. • Each full question consists of 16 marks. • There will be 2 full questions (with a maximum of Three sub questions) from each module. • Each full question will have sub questions covering all the topics under a module. The students will have to answer 5 full questions, selecting one full question from each module. 	
Text Books: <ol style="list-style-type: none"> 1. Digital Logic Applications and Design, John M Yarbrough, Thomson Learning, 2001. ISBN 981-240-062-1. 2. Donald D. Givone, "Digital Principles and Design", McGraw Hill, 2002. ISBN 978-0-07-052906-9. 	
Reference Books: <ol style="list-style-type: none"> 1. D. P. Kothari and J. S Dhillon, "Digital Circuits and Design", Pearson, 2016, ISBN:9789332543539. 2. Morris Mano, "Digital Design", Prentice Hall of India, Third Edition. 3. Charles H Roth, Jr., "Fundamentals of logic design", Cengage Learning. 4. K. A. Navas, "Electronics Lab Manual", Volume I, PHI, 5th Edition, 2015, ISBN: 9788120351424. 	

NETWORK ANALYSIS [As per Choice Based Credit System (CBCS) scheme] SEMESTER – III (EC/TC)			
Subject Code	15EC34	IA Marks	20
Number	04	Exam Marks	80
Total Number of Lecture Hours	50 (10 Hours per Module)	Exam Hours	03
CREDITS – 04			
Course objectives: This course enables students to: <ul style="list-style-type: none"> Describe basic network concepts emphasizing source transformation, source shifting, mesh and nodal techniques to solve for resistance/impedance, voltage, current and power. Explain network Thevenin's, Millman's, Superposition, Reciprocity, Maximum Power transfer and Norton's Theorems and apply them in solving the problems related to Electrical Circuits. Explain the behavior of networks subjected to transient conditions. Use applications of Laplace transforms to network problems. Describe Series and Parallel Combination of Passive Components as resonating circuits, related parameters and to analyze frequency response. Study two port network parameters like Z, Y, T and h and their inter-relationships and applications. 			
Modules			RBT Level
Module -1			
Basic Concepts: Practical sources, Source transformations, Network reduction using Star – Delta transformation, Loop and node analysis with linearly dependent and independent sources for DC and AC networks, Concepts of super node and super mesh.			L1, L2,L3,L4
Module -2			
Network Theorems: Superposition, Reciprocity, Millman's theorems, Thevinin's and Norton's theorems, Maximum Power transfer theorem.			L1, L2, L3,L4
Module -3			
Transient behavior and initial conditions: Behavior of circuit elements under switching condition and their Representation, evaluation of initial and final conditions in RL, RC and RLC circuits for AC and DC excitations. Laplace Transformation & Applications: Solution of networks, step, ramp and impulse responses, waveform Synthesis.			L1, L2, L3,L4
Module -4			
Resonant Circuits: Series and parallel resonance, frequency- response of series and Parallel circuits, Q-Factor, Bandwidth.			L1, L2, L3,L4
Module -5			

Two port network parameters: Definition of Z, Y, h and Transmission parameters, modeling with these parameters, relationship between parameters sets.	L1, L2, L3, L4
<p>Course Outcomes: After studying this course, students will be able to:</p> <ul style="list-style-type: none"> • Determine currents and voltages using source transformation/ source shifting/ mesh/ nodal analysis and reduce given network using star-delta transformation/ source transformation/ source shifting. • Solve network problems by applying Superposition/ Reciprocity/ Thevenin's/ Norton's/ Maximum Power Transfer/ Millman's Network Theorems and electrical laws to reduce circuit complexities and to arrive at feasible solutions. • Calculate current and voltages for the given circuit under transient conditions. • Apply Laplace transform to solve the given network. • Evaluate for RLC elements/ frequency response related parameters like resonant frequency, quality factor, half power frequencies, voltage across inductor and capacitor, current through the RLC elements, in resonant circuits • Solve the given network using specified two port network parameter like Z or Y or T or h. 	
<p>Question paper pattern:</p> <ul style="list-style-type: none"> • The question paper will have ten questions. • Each full question consists of 16 marks. • There will be 2 full questions (with a maximum of Three sub questions) from each module. • Each full question will have sub questions covering all the topics under a module. • The students will have to answer 5 full questions, selecting one full question from each module. 	
<p>Text Books:</p> <ol style="list-style-type: none"> 1. M.E. Van Valkenberg (2000), "Network analysis", Prentice Hall of India, 3rd edition, 2000, ISBN: 9780136110958. 2. Roy Choudhury, "Networks and systems", 2nd edition, New Age International Publications, 2006, ISBN: 9788122427677. 	
<p>Reference Books:</p> <ol style="list-style-type: none"> 1. Hayt, Kemmerly and Durbin "Engineering Circuit Analysis", TMH 7th Edition, 2010. 2. J. David Irwin /R. Mark Nelms, "Basic Engineering Circuit Analysis", John Wiley, 8thed, 2006. 3. Charles K Alexander and Mathew N O Sadiku, " Fundamentals of Electric Circuits", Tata McGraw-Hill, 3rd Ed, 2009. 	

ELECTRONIC INSTRUMENTATION [As per Choice Based Credit System (CBCS) scheme] SEMESTER – III (EC/TC)			
Subject Code	15EC35	IA Marks	20
Number of Lecture Hours/Week	04	Exam Marks	80
Total Number of Lecture Hours	50 (10 Hours per Module)	Exam Hours	03
CREDITS – 04			
Course objectives: This course will enable students to: <ul style="list-style-type: none"> • Define and describe accuracy and precision, types of errors, statistical and probability analysis. • Describe the operation of Ammeters, Voltmeters, Multimeters and develop circuits for multirange Ammeters and Voltmeters. • Describe functional concepts and operation of various Analog and Digital measuring instruments. • Describe basic concepts and operation of Digital Voltmeters and Microprocessor based instruments. • Describe and discuss functioning and types of Oscilloscopes, Signal generators, AC and DC bridges. • Recognize and describe significance and working of different types of transducers. 			
Modules			RBT Level
Module -1 Measurement and Error: Definitions, Accuracy, Precision, Resolution and Significant Figures, Types of Errors, Measurement error combinations, Basics of Statistical Analysis. (Text 2) Ammeters: DC Ammeter, Multirange Ammeter, The Ayrton Shunt or Universal Shunt, Requirements of Shunt, Extending of Ammeter Ranges, RF Ammeter (Thermocouple), Limitations of Thermocouple. (Text 1) Voltmeters and Multimeters: Introduction, Basic Meter as a DC Voltmeter, DC Voltmeter, Multirange Voltmeter, Extending Voltmeter Ranges, Loading, AC Voltmeter using Rectifiers. Transistor Voltmeter, Differential Voltmeter, True RMS Voltmeter, Considerations in Choosing an Analog Voltmeter, Multimeter. (Text 1)			L1, L2, L3
Module -2			

<p>Digital Voltmeters: Introduction, RAMP technique, Dual Slope Integrating Type DVM, Integrating Type DVM, Most Commonly used principles of ADC, Successive Approximations, Continuous Balance DVM, $3\frac{1}{2}$-Digit, Resolution and Sensitivity of Digital Meters, General Specifications of DVM, Microprocessor based Ramp type DVM. (Text 1)</p> <p>Digital Instruments: Introduction, Digital Multimeters, Digital Frequency Meter, Digital Measurement of Time, Universal Counter, Digital Tachometer, Digital pH Meter, Digital Phase Meter, Digital Capacitance Meter, Microprocessor based Instruments. (Text 1)</p>	<p>L1, L2,L3</p>
<p>Module -3</p>	
<p>Oscilloscopes: Introduction, Basic principles, CRT features, Block diagram of Oscilloscope, Simple CRO, Vertical Amplifier, Horizontal Deflecting System, Sweep or Time Base Generator, Storage Oscilloscope, Digital Readout Oscilloscope, Measurement of Frequency by Lissajous Method, Digital Storage Oscilloscope. (Text 1)</p> <p>Signal Generators: Introduction, Fixed and Variable AF Oscillator, Standard Signal Generator, Laboratory Type Signal Generator, AF sine and Square Wave Generator, Function Generator, Square and Pulse Generator, Sweep Generator. (Text 1)</p>	<p>L1, L2</p>
<p>Module -4</p>	
<p>Measuring Instruments: Output Power Meters, Field Strength Meter, Stroboscope, Phase Meter, Vector Impedance Meter, Q Meter, Megger, Analog pH Meter. (Text 1)</p> <p>Bridges: Introduction, Wheatstone's bridge, Kelvin's Bridge; AC bridges, Capacitance Comparison Bridge, Inductance Comparison Bridge, Maxwell's bridge, Wien's bridge, Wagner's earth connection. (Text 1)</p>	<p>L1, L2,L3</p>
<p>Module -5</p>	
<p>Transducers: Introduction, Electrical transducers, Selecting a transducer, Resistive transducer, Resistive position transducer, Strain gauges, Resistance thermometer, Thermistor, Inductive transducer, Differential output transducers, LVDT, Piezoelectric transducer, Photoelectric transducer, Photovoltaic transducer, Semiconductor photo diode and transistor, Temperature transducers-RTD. (Text 1)</p>	<p>L1, L2, L3</p>
<p>Course Outcomes: After studying this course, students will be able to:</p> <ul style="list-style-type: none"> • Describe instrument measurement errors and calculate them. • Describe the operation of Ammeters, Voltmeters, Multimeters and develop circuits for multirange Ammeters and Voltmeters. • Describe functional concepts and operation of Digital voltmeters and instruments to measure voltage, frequency, time period, phase difference of signals, rotation speed, capacitance and pH of solutions. • Describe functional concepts and operation of various Analog measuring instruments to measure output power, field Strength, impedance, stroboscopic speed, in/out of phase, Q of coils, insulation resistance and pH. • Describe and discuss functioning and types of Oscilloscopes, Signal generators and Transducers. • Utilize AC and DC bridges for passive component and frequency measurements. 	

Question paper pattern:

- The question paper will have ten questions.
- Each full question consists of 16 marks.
- There will be 2 full questions (with a maximum of Three sub questions) from each module.
- Each full question will have sub questions covering all the topics under a module.
- The students will have to answer 5 full questions, selecting one full question from each module.

Text Books:

1. H. S. Kalsi, "Electronic Instrumentation", McGraw Hill, 3rd Edition, 2012, ISBN:9780070702066.
2. David A. Bell, "Electronic Instrumentation & Measurements", Oxford University Press PHI 2nd Edition, 2006, ISBN 81-203-2360-2.

Reference Books:

1. A. D. Helfrick and W.D. Cooper, "Modern Electronic Instrumentation and Measuring Techniques", Pearson, 1st Edition, 2015, ISBN:9789332556065.
2. A. K. Sawhney, "Electronics and Electrical Measurements", Dhanpat Rai & Sons. ISBN -81-7700-016-0

ENGINEERING ELECTROMAGNETICS [As per Choice Based Credit System (CBCS) scheme] SEMESTER – III (EC/TC)			
Subject Code	15EC36	IA Marks	20
Number of Lecture Hours/Week	04	Exam Marks	80
Total Number of Lecture Hours	50 (10 Hours per Module)	Exam Hours	03
CREDITS – 04			
Course objectives: This course will enable students to: <ul style="list-style-type: none"> • Study the different coordinate systems, Physical significance of Divergence, Curl and Gradient. • Understand the applications of Coulomb's law and Gauss law to different charge distributions and the applications of Laplace's and Poisson's Equations to solve real time problems on capacitance of different charge distributions. • Understand the physical significance of Biot-Savart's, Amperes's Law and Stokes' theorem for different current distributions. • Infer the effects of magnetic forces, materials and inductance. • Know the physical interpretation of Maxwell's equations and applications for Plane waves for their behaviour in different media • Acquire knowledge of Poynting theorem and its application of power flow. 			
Modules			RBT Level
Module - 1			
Coulomb's Law, Electric Field Intensity and Flux density Experimental law of Coulomb, Electric field intensity, Field due to continuous volume charge distribution, Field of a line charge, Electric flux density.			L1, L2, L3
Module -2			
Gauss's law and Divergence Gauss' law, Divergence. Maxwell's First equation (Electrostatics), Vector Operator and divergence theorem. Energy, Potential and Conductors Energy expended in moving a point charge in an electric field, The line integral, Definition of potential difference and potential, The potential field of point charge, Current and Current density, Continuity of current.			L1, L2, L3
Module -3			
Poisson's and Laplace's Equations Derivation of Poisson's and Laplace's Equations, Uniqueness theorem, Examples of the solution of Laplace's equation. Steady Magnetic Field Biot-Savart Law, Ampere's circuital law, Curl, Stokes' theorem, Magnetic flux and magnetic flux density, Scalar and Vector Magnetic Potentials.			L1, L2, L3
Module -4			

Magnetic Forces Force on a moving charge, differential current elements, Force between differential current elements.	L1, L2, L3
Magnetic Materials Magnetisation and permeability, Magnetic boundary conditions, Magnetic circuit, Potential Energy and forces on magnetic materials.	
Module -5	
Time-varying fields and Maxwell's equations Faraday's law, displacement current, Maxwell's equations in point form, Maxwell's equations in integral form.	L1, L2, L3
Uniform Plane Wave Wave propagation in free space and good conductors. Poynting's theorem and wave power, Skin Effect.	
Course Outcomes: After studying this course, students will be able to: <ul style="list-style-type: none"> • Evaluate problems on electric field due to point, linear, volume charges by applying conventional methods or by Gauss law. • Determine potential and energy with respect to point charge and capacitance using Laplace equation. • Calculate magnetic field, force, and potential energy with respect to magnetic materials. • Apply Maxwell's equation for time varying fields, EM waves in free space and conductors. • Evaluate power associated with EM waves using Poynting theorem. 	
Question paper pattern: <ul style="list-style-type: none"> • The question paper will have ten questions. • Each full question consisting of 16 marks. • There will be 2 full questions (with a maximum of Three sub questions) from each module. • Each full question will have sub questions covering all the topics under a module. • The students will have to answer 5 full questions, selecting one full question from each module. 	
Text Book: W.H. Hayt and J.A. Buck, "Engineering Electromagnetics", 7th Edition, Tata McGraw-Hill, 2009, ISBN-978-0-07-061223-5.	
Reference Books: <ol style="list-style-type: none"> 1. John Krauss and Daniel A Fleisch, " Electromagnetics with applications", McGraw-Hill. 2. N. Narayana Rao, "Fundamentals of Electromagnetics for Engineering", Pearson. 	

ANALOG ELECTRONICS LABORATORY [As per Choice Based Credit System (CBCS) scheme] SEMESTER – III (EC/TC)			
Laboratory Code	15ECL37	IA Marks	20
Number of Lecture Hours/Week	01Hr Tutorial (Instructions) + 02 Hours Laboratory	Exam Marks	80
RBT Level	L1, L2, L3	Exam Hours	03
CREDITS – 02			
Course objectives: This laboratory course enables students to get practical experience in design, assembly, testing and evaluation of: <ul style="list-style-type: none"> • Rectifiers and Voltage Regulators. • BJT characteristics and Amplifiers. • JFET Characteristics and Amplifiers. • MOSFET Characteristics and Amplifiers • Power Amplifiers. • RC-Phase shift, Hartley, Colpitts and Crystal Oscillators. 			
NOTE: The experiments are to be carried using discrete components only.			
Laboratory Experiments:			
1. Design and set up the following rectifiers with and without filters and to determine ripple factor and rectifier efficiency: (a) Full Wave Rectifier (b) Bridge Rectifier			
2. Conduct experiment to test diode clipping (single/double ended) and clamping circuits (positive/negative).			
3. Conduct an experiment on Series Voltage Regulator using Zener diode and power transistor to determine line and load regulation characteristics.			
4. Realize BJT Darlington Emitter follower with and without bootstrapping and determine the gain, input and output impedances.			
5. Design and set up the BJT common emitter amplifier using voltage divider bias with and without feedback and determine the gain- bandwidth product from its frequency response.			
6. Plot the transfer and drain characteristics of a JFET and calculate its drain resistance, mutual conductance and amplification factor.			
7. Design, setup and plot the frequency response of Common Source JFET/MOSFET amplifier and obtain the bandwidth.			

8. Plot the transfer and drain characteristics of n-channel MOSFET and calculate its parameters, namely; drain resistance, mutual conductance and amplification factor.
9. Set-up and study the working of complementary symmetry class B push pull power amplifier and calculate the efficiency.
10. Design and set-up the RC-Phase shift Oscillator using FET, and calculate the frequency of output waveform.
11. Design and set-up the following tuned oscillator circuits using BJT, and determine the frequency of oscillation. (a) Hartley Oscillator (b) Colpitts Oscillator
12. Design and set-up the crystal oscillator and determine the frequency of oscillation.
<p>Course Outcomes: On the completion of this laboratory course, the students will be able to:</p> <ul style="list-style-type: none"> • Test circuits of rectifiers, clipping circuits, clamping circuits and voltage regulators. • Determine the characteristics of BJT and FET amplifiers and plot its frequency response. • Compute the performance parameters of amplifiers and voltage regulators • Design and test the basic BJT/FET amplifiers, BJT Power amplifier and oscillators.
<p>Conduct of Practical Examination:</p> <ul style="list-style-type: none"> • All laboratory experiments are to be included for practical examination. • Students are allowed to pick one experiment from the lot. • Strictly follow the instructions as printed on the cover page of answer script for breakup of marks. • Change of experiment is allowed only once and Marks allotted to the procedure part to be made zero.

DIGITAL ELECTRONICS LABORATORY [As per Choice Based Credit System (CBCS) scheme] SEMESTER – III (EC/TC)			
Laboratory Code	15ECL38	IA Marks	20
Number of Lecture Hours/Week	01Hr Tutorial (Instructions) + 02 Hours Laboratory	Exam Mark	80
RBT Level	L1, L2, L3	Exam Hour	03
CREDITS – 02			
Course objectives: This laboratory course enables students to get practical experience in design, realisation and verification of <ul style="list-style-type: none"> • Demorgan's Theorem, SOP, POS forms • Full/Parallel Adders, Subtractors and Magnitude Comparator • Multiplexer using logic gates • Demultiplexers and Decoders • Flip-Flops, Shift registers and Counters 			
NOTE: <ol style="list-style-type: none"> 1. Use discrete components to test and verify the logic gates. The IC numbers given are suggestive. Any equivalent IC can be used. 2. For experiment No. 11 and 12 any open source or licensed simulation tool may be used. 			
Laboratory Experiments:			
1. Verify (a) Demorgan's Theorem for 2 variables. (b) The sum-of product and product-of-sum expressions using universal gates.			
2. Design and implement (a) Full Adder using basic logic gates. (b) Full subtractor using basic logic gates.			
3. Design and implement 4-bit Parallel Adder/ subtractor using IC 7483.			
4. Design and Implementation of 4-bit Magnitude Comparator using IC 7485.			
5. Realize (a) 4:1 Multiplexer using gates. (b) 3-variable function using IC 74151(8:1MUX).			
6. Realize 1:8 Demux and 3:8 Decoder using IC74138.			
7. Realize the following flip-flops using NAND Gates. (a) Clocked SR Flip-Flop (b) JK Flip-Flop.			
8. Realize the following shift registers using IC7474 (a) SISO (b) SIPO (c) PISO (d) PIPO.			
9. Realize the Ring Counter and Johnson Counter using IC7476.			
10. Realize the Mod-N Counter using IC7490.			

11. Simulate Full- Adder using simulation tool.

12. Simulate Mod-8 Synchronous UP/DOWN Counter using simulation tool.

Course outcomes: On the completion of this laboratory course, the students will be able to:

- Demonstrate the truth table of various expressions and combinational circuits using logic gates.
- Design and test various combinational circuits such as adders, subtractors, comparators, multiplexers and demultiplexers.
- Construct and test flips-flops, counters and shift registers.
- Simulate full adder and up/down counters.

Conduct of Practical Examination:

- All laboratory experiments are to be included for practical examination.
- Students are allowed to pick one experiment from the lot.
- Strictly follow the instructions as printed on the cover page of answer script for breakup of marks.
- Change of experiment is allowed only once and 15% Marks allotted to the procedure part to be made zero.